# V10K60DU

Vishay General Semiconductor

## High Current Density Surface-Mount Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.39$  V at  $I_F = 2.5$  A



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## **DESIGN SUPPORT TOOLS**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5 A				
V <sub>RRM</sub>	60 V				
I <sub>FSM</sub>	100 A				
V <sub>F</sub> at I <sub>F</sub> = 5 A (T <sub>A</sub> = 125 °C)	0.48 V				
T <sub>J</sub> max.	150 °C				
Package	FlatPAK 5 x 6				
Circuit configuration	Separated cathode				

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



AUTOMOTIVE GRADE

Available

- AEC-Q101 qualified available
  Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

### **MECHANICAL DATA**

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V10K60DU	UNIT		
Device marking code		V1060D			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	60	V		
Maximum DC forward aureant par diada	I <sub>F(AV)</sub> <sup>(1)</sup>	5	А		
Maximum DC forward current per diode	I <sub>F(AV)</sub> <sup>(2)</sup>	2.8	А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	100	А		
Operating junction temperature range	T <sub>J</sub> <sup>(3)</sup>	-40 to +150	°C		
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C		

#### Notes

(1) With infinite heatsink

<sup>(2)</sup> Free air, mounted on recommended pad area

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{0JA}$ 

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1

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ELECTRICAL CHARACTERIST	TICS (T <sub>A</sub> = 25	5 °C unless of	herwise note	d)		
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T₄ = 25 °C		0.48	-	
	I <sub>F</sub> = 5 A	V <sub>E</sub> (1)	0.54	0.62	V	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C	VF <sup>()</sup>	0.39	-	v
	I <sub>F</sub> = 5 A			0.48	0.56	
Reverse current per diode	V = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	0.4	mA
neverse current per diode		T <sub>A</sub> = 125 °C		5	15	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	560	-	pF

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Thermal registeres per diade	R <sub>0JA</sub> (1)(2)	100	-	°C/W
Thermal resistance per diode	stance per diode R <sub>0JM</sub> <sup>(3)</sup> 3.0	4.0	0/11	

#### Notes

 $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

 $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  - junction-to-ambient

 $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

ORDERING INFO	RDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10K60DU-M3/H	0.10	Н	1500	7" diameter plastic tape and reel		
V10K60DU-M3/I	0.10	I	6000	13" diameter plastic tape and reel		
V10K60DUHM3/H (1)	0.10	н	1500	7" diameter plastic tape and reel		
V10K60DUHM3/I <sup>(1)</sup>	0.10	l	6000	13" diameter plastic tape and reel		

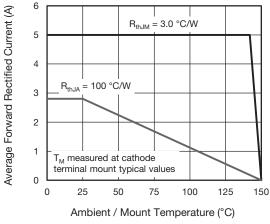
Note

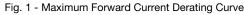
(1) AEC-Q101 qualified



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)





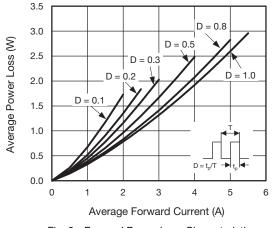
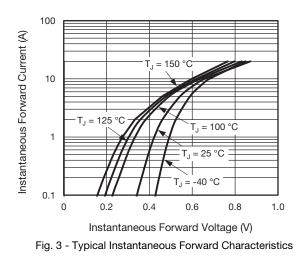


Fig. 2 - Forward Power Loss Characteristics



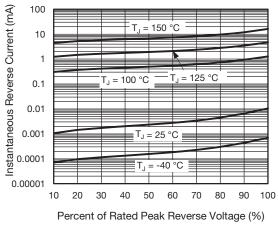
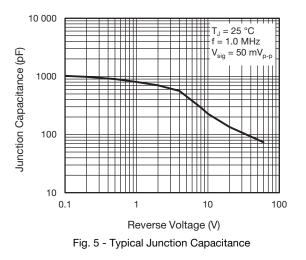
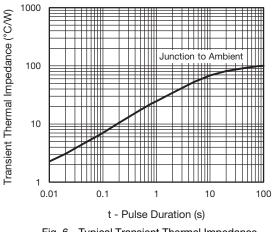
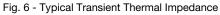


Fig. 4 - Typical Reverse Leakage Characteristics







Revision: 26-Jul-2018

3

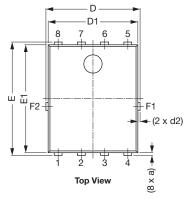
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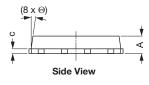
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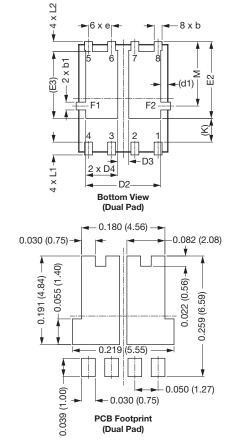


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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







DIM. MIN.	INCHES			MILLIMETERS			
	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.035	0.039	0.043	0.89	0.99	1.09	
(a)	-	0.006	-	-	0.15	-	
b	0.013	0.017	0.020	0.32	0.43	0.52	
b1	0.013	0.017	0.020	0.32	0.43	0.52	
С	0.008	-	0.014	0.20	-	0.35	
D	0.197	0.203	0.209	5.00	5.15	5.30	
D1	0.189	0.193	0.197	4.80	4.90	5.00	
D2	0.154	0.161	0.169	3.90	4.10	4.30	
D3	0.020	0.024	0.031	0.50	0.60	0.80	
D4	0.063	0.069	0.075	1.60	1.75	1.90	
(d1)	-	0.016	-	-	0.40	-	
(d2)	-	0.005	-	-	0.125	-	
E	0.238	0.244	0.250	6.05	6.20	6.35	
E1	0.228	0.232	0.236	5.80	5.90	6.00	
E2	0.157	0.165	0.173	4.00	4.20	4.40	
(E3)	-	0.144	-	-	3.65	-	
е	0.050 BSC				1.27 BSC		
(K)	0.039	-	-	1.00	-	-	
L1	0.019	-	0.043	0.48	-	1.10	
L2	0.012	-	0.031	0.30	-	0.80	
М	0.128	0.138	0.148	3.25	3.50	3.75	
Θ	0°	-	10°	0°	-	10°	

#### Notes

• Dimensioning and tolerancing per ASME Y14.5-2009

Dimensions D1 and E1 do not include mold flash or gate burrs

• Dimension (XX) means reference only

Revision: 26-Jul-2018

4

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